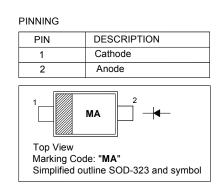
SCHOTTKY BARRIER DIODE

Features

- High reliability
- · Low forward voltage and reverse current

Applications

- For electronic calculator, etc.
- · Low current rectification and high speed switching



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V _{RM}	45	V
Reverse Voltage	V _R	10	V
Average Rectified Output Current	Ι _Ο	50	mA
Peak Forward Current	I _{FM}	150	mA
Surge Forward Current	I _{surge}	500	mA
Junction Temperature	Tj	125	°C
Storage Temperature Range	Ts	- 55 to + 125	°C

Characteristics at T_a = 25 °C

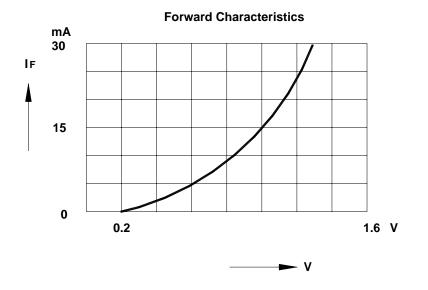
Parameter	Symbol	Min.	Max.	Unit
Forward Current at V _F = 1 V	١ _F	4	-	mA
Reverse Current at V _R = 10 V	I _R	-	50	μA
Reverse Voltage at I _R = 100 μA	V _R	45	-	V
Junction Capacitance at f = 1 MHz, V = -1 V	CJ	-	1	pF
Rectification efficiency at Vi = 2 Vrms, R = 5 KΩ, C = 20 pF, f = 40 MHz	η	55	-	%

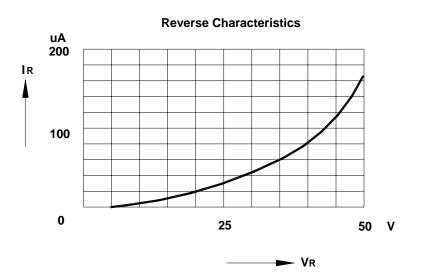






Dated : 01/09/2006









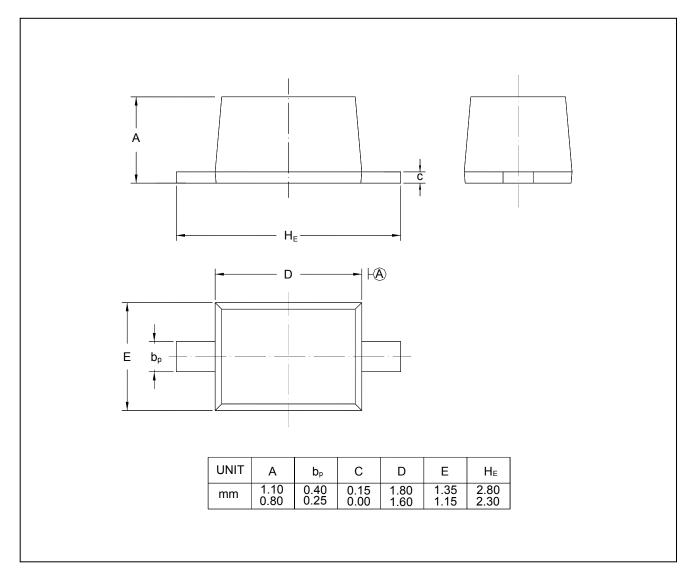


Dated : 01/09/2006

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323





SEMTECH ELECTRONICS LTD. (Subsidiary of Sino-Tech International Holdings Limited, a company





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